

## FEATURES

- adjustable gain from 0 to 60 dB
- 0.94 V DC voltage regulator on-chip
- attack time fixed at less than 1 ms
- release time adjustable from 40 to 500 ms
- low input referred noise 1.2  $\mu$ V
- <1 % distortion at 10 mVRMS output
- operates from 1.05 to 3 VDC

## STANDARD PACKAGING

- 8 pin MICROpac
- 8 pin MINIpac
- 8 pin PLID<sup>®</sup>
- 8 pin SLT
- Chip (64 x 62 mils)

Au Bump

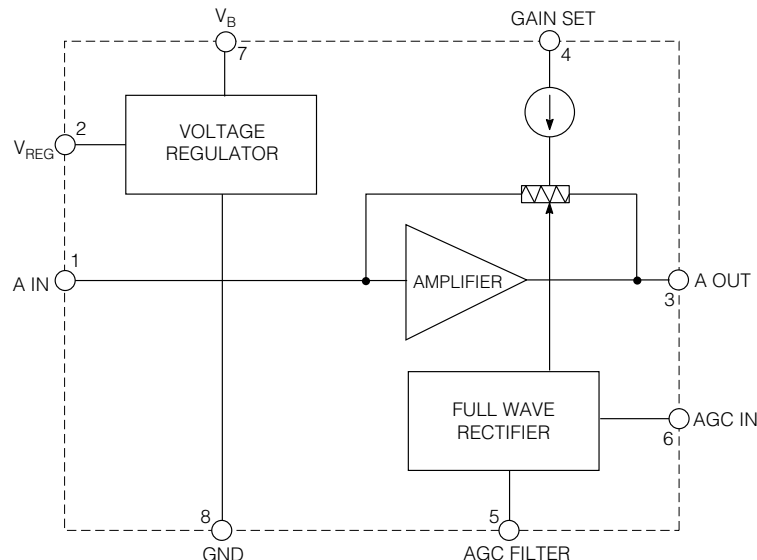
## DESCRIPTION

The LD502 is a compression (AGC) preamplifier that consists of a single ended input inverting amplifier, with an internal current controlled resistance connected between input and output.

By using  $R_{GT}$  (see test circuit) to vary the value of this current controlled resistance, the amplifier gain and compression threshold can be controlled over a range of 60 dB.

The AGC current is derived from a full wave rectifier driven by a differential amplifier. The attack time of the AGC circuit is fixed at less than 1 ms. The release time is adjustable from 40 to 500 ms by selecting the value of an external capacitor (C3).

Internally, a series shunt voltage regulator produces a 0.94 V DC regulated output voltage. This provides a bias for electret microphones and permits circuit operations over a wide range of supply voltages, 1.05 to 3 VDC for LD502 without any degradation of electrical performances.



## BLOCK DIAGRAM

 Patented 1985  
 Canada 1183580

 Patent Pending Europe 83.300836.0  
 USA 4506169 Japan 58-06886

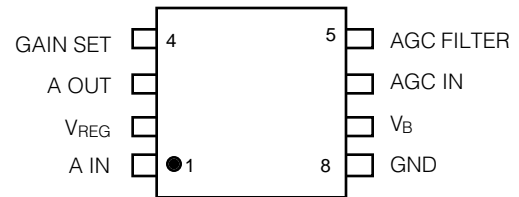
## ABSOLUTE MAXIMUM RATINGS

PARAMETER	VALUE/UNITS
Supply Voltage	3 V DC
Power Dissipation	25 mW
Operating Temperature Range	-10°C to 50° C
Storage Temperature Range	-20°C to 70° C

**CAUTION**  
CLASS 1 ESD SENSITIVITY



## PIN CONNECTION



## ELECTRICAL CHARACTERISTICS

Conditions: Frequency = 1 kHz, Temperature = 25°C, Supply Voltage  $V_B = 1.3$  VDC

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Gain	$A_v$	$V_{OUT} = 11.0$ mV, $20 \log \left( \frac{V_{OUT}}{V_{IN}} \right)$	38	41	46	dB
Output Level	$V_{OHIGH}$	$V_{IN} = 6.32$ mV, S1 closed	7.5	12	15.5	mV
Distortion -Linear	THD	$V_{OUT} = 11.0$ mV	-	1	2.9	%
- AGC		$V_{IN} = 6.32$ mV, S1 closed	-	1	2.2	%
Input Referred Noise	IRN	S2 closed, NFB 0.2 to 10 kHz at 12 dB/Oct	-	1.2	2.2	$\mu$ V
Compression Function Ratio		$V_{IN} = 0.1$ to 6.32 mV, S1 closed	2	5	8	dB
Total Amplifier Current	$I_{AMP}$		160	310	380	$\mu$ A
Regulated Voltage	$V_{REG}$		0.890	0.940	0.990	VDC
Supply Rejection	PSRR		51	60	-	dB

All parameters and switches remain as shown in Test Circuit unless otherwise stated in "Conditions" column

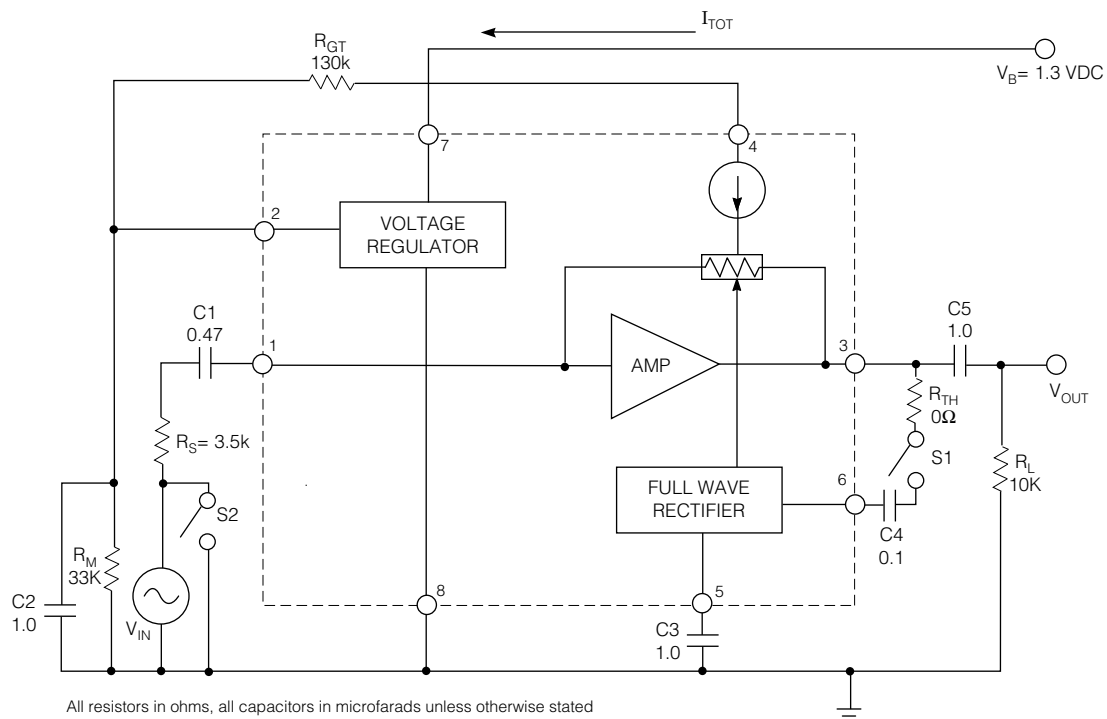


Fig. 1 Test Circuit



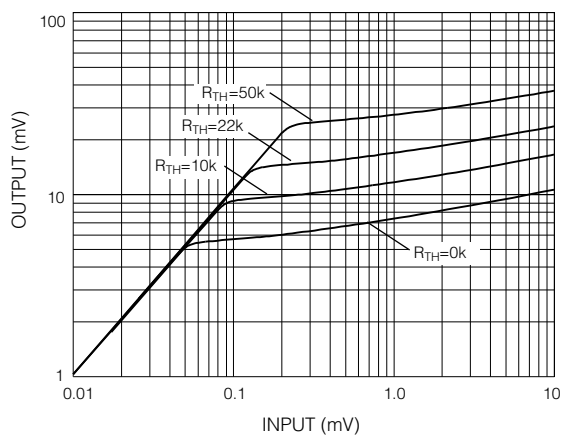


Fig. 4 I/O Characteristics at Various  $R_{TH}$  Values

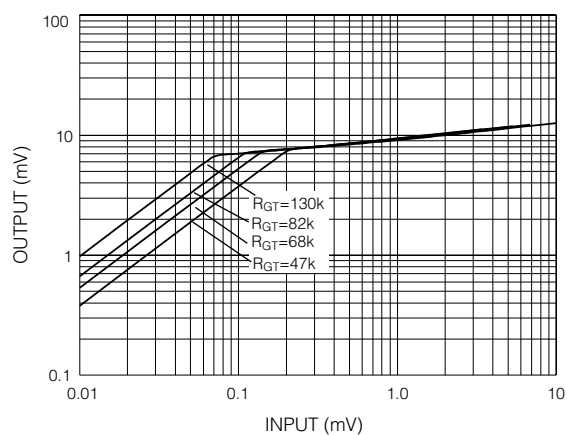


Fig. 5 I/O Characteristics at Various  $R_{GT}$  Values

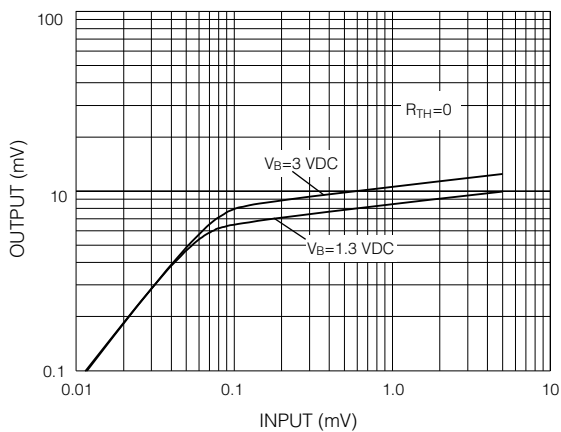


Fig. 6 Effects of Supply Voltage Variation

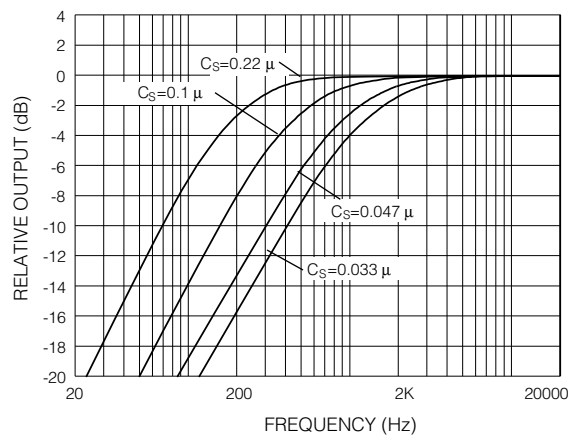


Fig. 7 Frequency Response at Various  $C_S$  Values

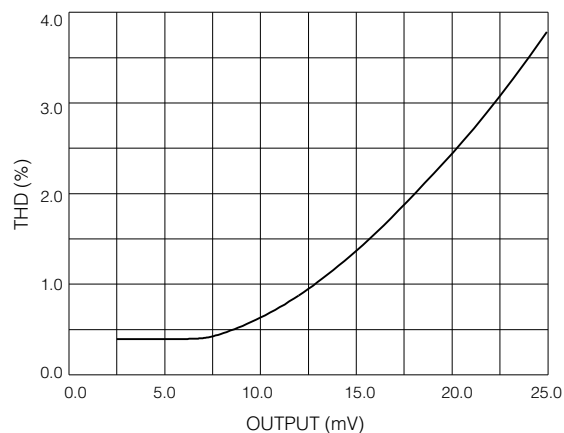


Fig. 8 Total Harmonic Distortion vs Output Level

#### REVISION NOTES

Changes to Fig.1, test conditions, Pb/Sn bump removed.

#### DOCUMENT IDENTIFICATION

##### PRODUCT PROPOSAL

This data has been compiled for market investigation purposes only, and does not constitute an offer for sale.

##### ADVANCE INFORMATION NOTE

This product is in development phase and specifications are subject to change without notice. Gennum reserves the right to remove the product at any time. Listing the product does not constitute an offer for sale.

##### PRELIMINARY DATA SHEET

The product is in a preproduction phase and specifications are subject to change without notice.

##### DATA SHEET

The product is in production. Gennum reserves the right to make changes at any time to improve reliability, function or design, in order to provide the best product possible.